

HD74HC682, HD74HC684

8-bit Magnitude Comparator

REJ03D0642-0200
 (Previous ADE-205-528)
 Rev.2.00
 Mar 30, 2006

Description

These magnitude comparators perform comparisons of two eight-bit binary or BCD words. All types provide $\overline{P=Q}$ outputs and provide $\overline{P>Q}$ outputs. The HD74HC682 features 20 k Ω pullup termination resistors on the Q inputs for analog or switch data.

Type	$\overline{P=Q}$	$\overline{P>Q}$	Output Enable	20 k Ω Pullup
HD74HC682	Yes	Yes	No	Yes
HD74HC684	Yes	Yes	No	No

Features

- High Speed Operation
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max ($T_a = 25^\circ\text{C}$)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC682P HD74HC684P	DILP-20 pin	PRDP0020AC-B (DP-20NEV)	P	—
HD74HC682RPEL HD74HC684RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

Function Table

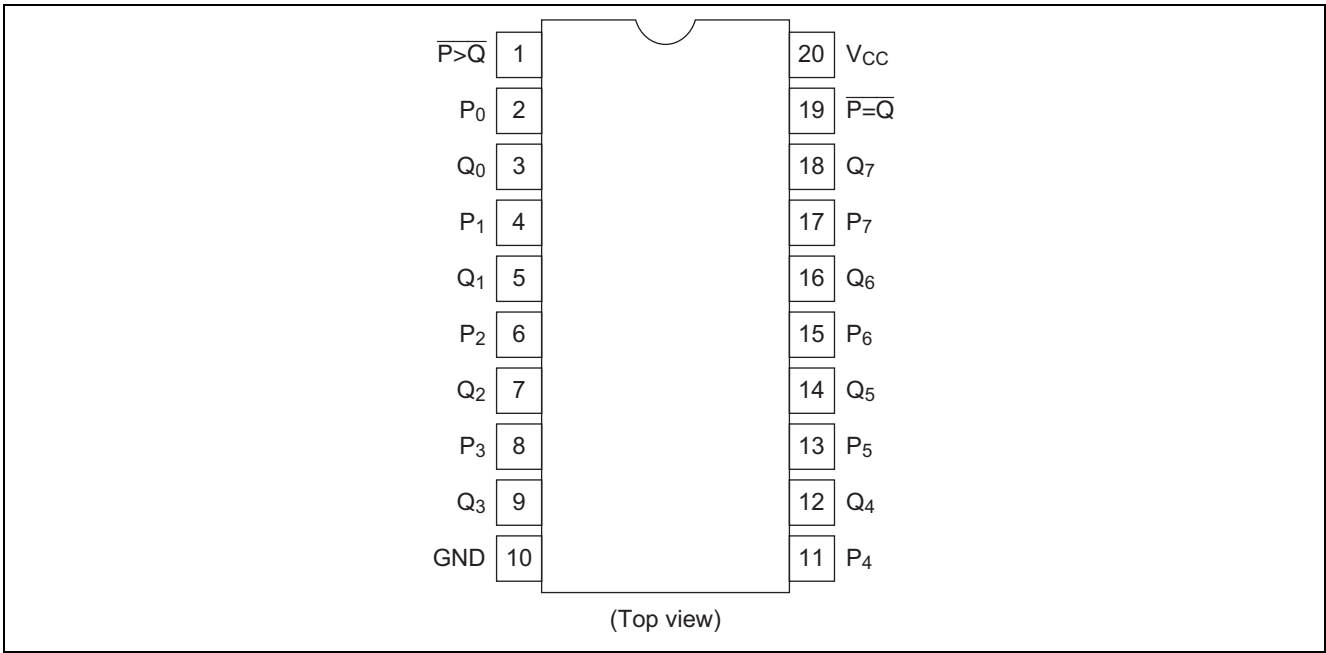
Input Data	Outputs	
P, Q	$\overline{P=Q}$	$\overline{P>Q}$
$P = Q$	L	H
$P > Q$	H	L
$P < Q$	H	H

Note: 1. The $\overline{P<Q}$ function can be generated by applying the $\overline{P=Q}$ and $\overline{P>Q}$ Outputs to a 2-input NAND gate.

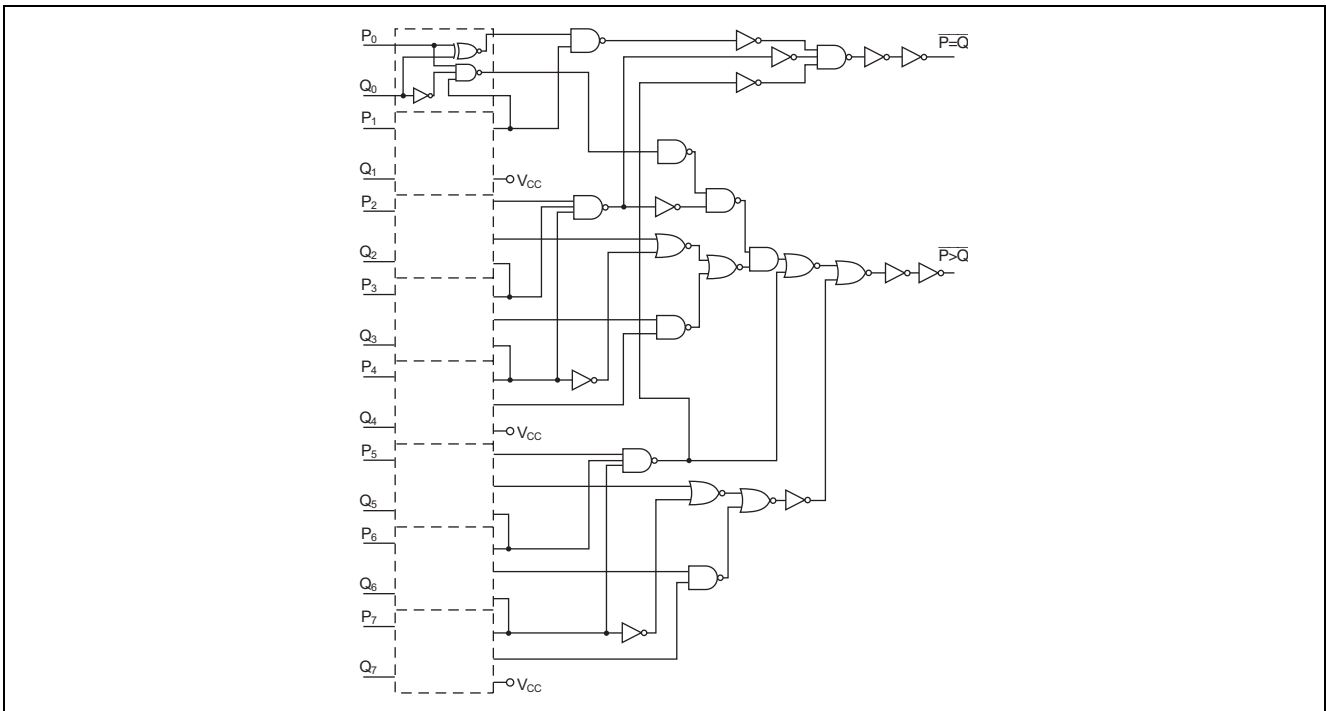
H : high level

L : low level

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
Input / Output voltage	V_{IN}, V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	I_{IK}, I_{OK}	± 20	mA
Output current	I_{OUT}	± 25	mA
V_{CC} , GND current	I_{CC} or I_{GND}	± 50	mA
Power dissipation	P_T	500	mW
Storage temperature	T_{stg}	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	T_a	-40 to 85	°C	
Input rise / fall time *1	t_r, t_f	0 to 1000	ns	$V_{CC} = 2.0$ V
		0 to 500		$V_{CC} = 4.5$ V
		0 to 400		$V_{CC} = 6.0$ V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

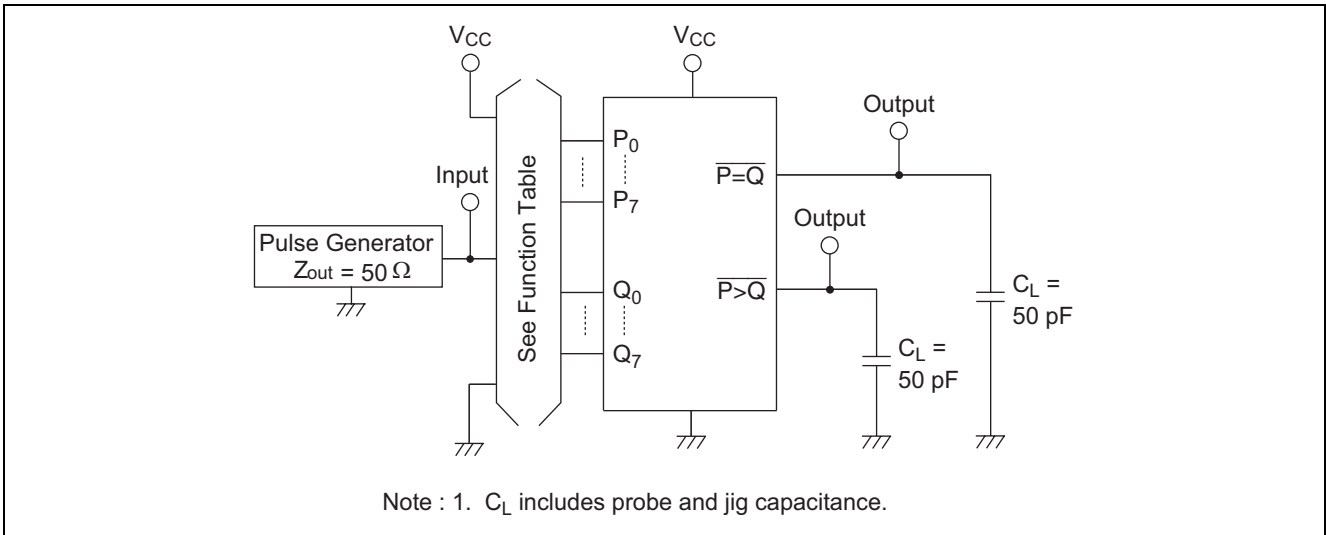
Electrical Characteristics

Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V _{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V _{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	V _{in} = V _{IH} or V _{IL}	I _{OH} = -20 μA
		4.5	4.4	4.5	—	4.4	—			I _{OH} = -4 mA
		6.0	5.9	6.0	—	5.9	—			I _{OH} = -5.2 mA
		4.5	4.18	—	—	4.13	—			
		6.0	5.68	—	—	5.63	—			
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	V _{in} = V _{IH} or V _{IL}	I _{OL} = 20 μA
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I _{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I _{OL} = 5.2 mA
Input current (HC684)	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	V _{in} = V _{CC} or GND	
Quiescent supply current (HC684)	I _{CC}	6.0	—	—	4.0	—	40	μA	V _{in} = V _{CC} or GND, I _{out} = 0 μA	
Input current (HD682)	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	V _{in} = V _{CC}	
			—	—	-0.6	—	-0.7	mA	I _{in} = GND	
Quiescent supply current (HC682)	I _{CC}	6.0	—	—	4.8	—	5.6	mA	Q _n = GND, other inputs = V _{CC} or GND I _{out} = 0 μA	
			—	—	4.0	—	40	μA	Q _n = V _{CC} , other inputs = V _{CC} or GND I _{out} = 0 μA	

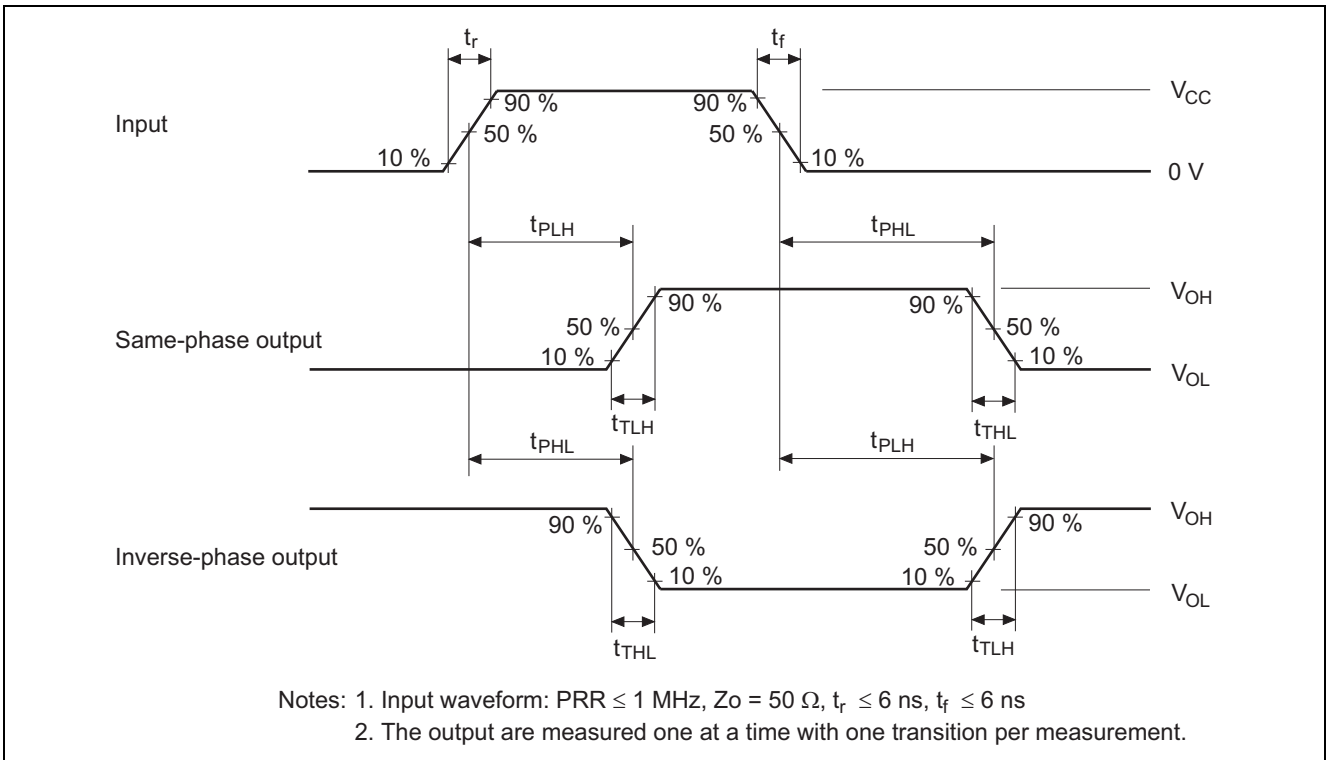
Switching Characteristics (C_L = 50 pF, Input t_r = t_f = 6 ns)

Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions			
			Min	Typ	Max	Min	Max					
Propagation delay time	t _{PLH}	2.0	—	—	175	—	220	ns	P or Q to $\overline{P=Q}$			
		4.5	—	—	35	—	44					
		6.0	—	—	30	—	37					
	t _{PHL}	2.0	—	—	200	—	250	ns			P or Q to $\overline{P>Q}$	
		4.5	—	—	40	—	50					
		6.0	—	—	34	—	43					
Output rise/fall time	t _{TLH}	2.0	—	—	60	—	75	ns				
		4.5	—	—	12	—	15					
		6.0	—	—	10	—	13					
Input capacitance	C _{in}	—	—	5	10	—	10	pF				

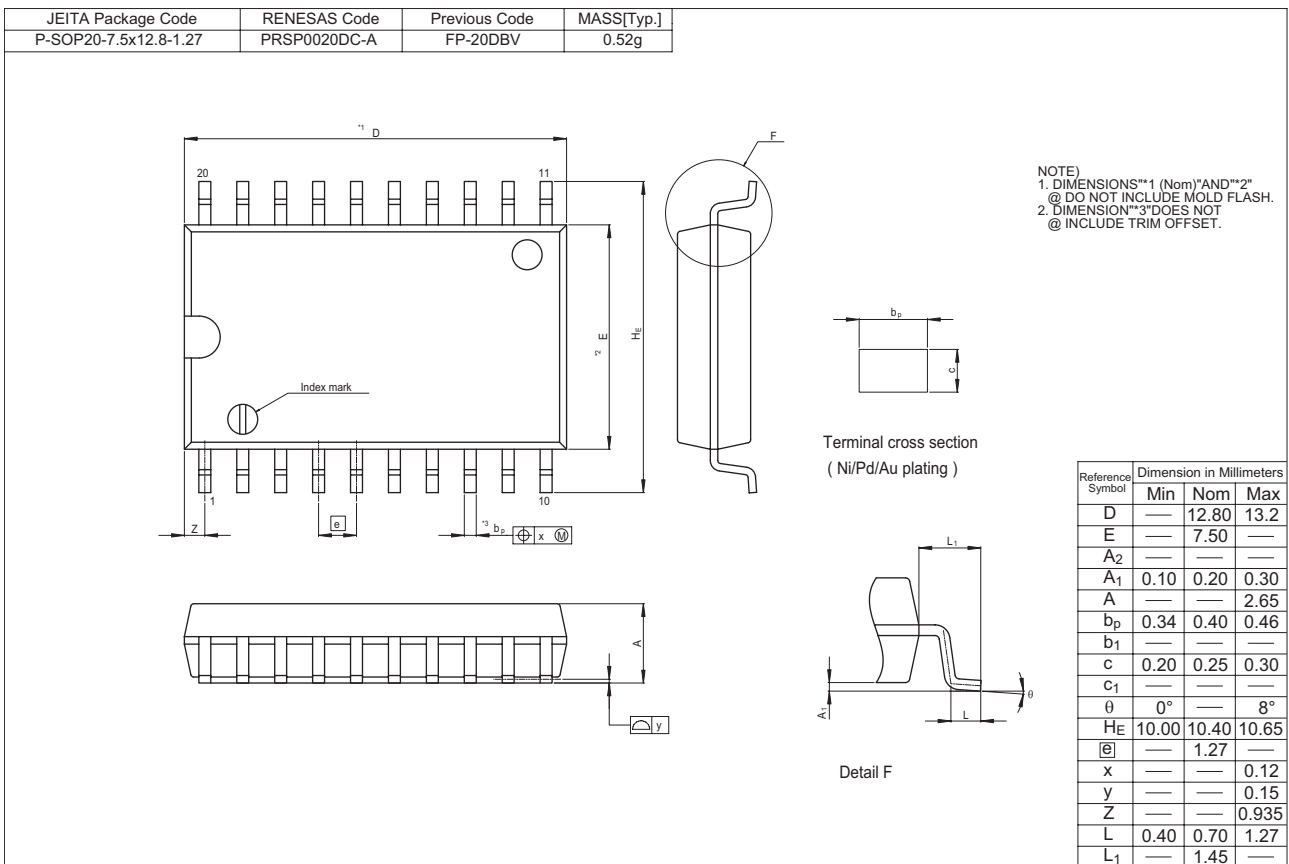
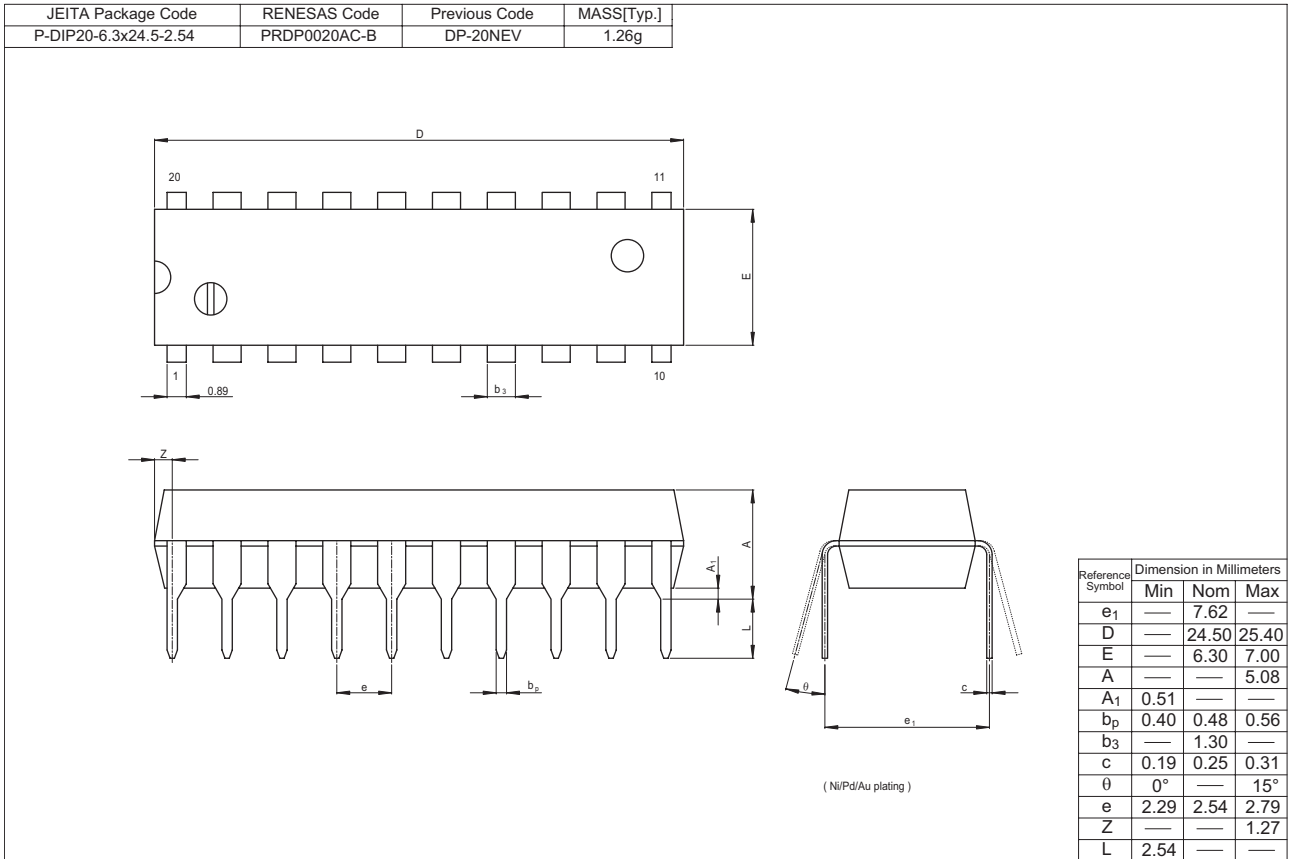
Test Circuit



Waveforms



Package Dimensions



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Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.

Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120
Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.

7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd.

10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd.

Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510